Silicon Switching Diode

- For high-speed switching applications

- Common anode configuration
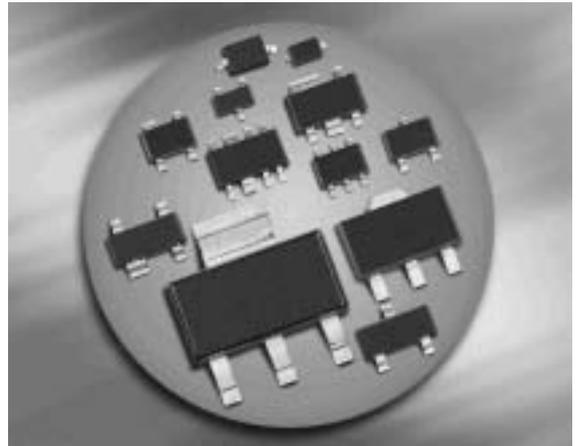
BAW56   **BAW56S**
BAW56T   **BAW56U**
BAW56W
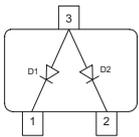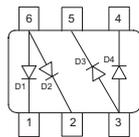
Type	Package	Configuration	Marking
BAW56	SOT23	common anode	A1s
BAW56S	SOT363	double common anode	A1s
BAW56T	SC75	common anode	A1s
BAW56U	SC74	double common anode	A1s
BAW56W	SOT323	common anode	A1s

Maximum Ratings at T_A = 25°C, unless otherwise specified

Parameter	Symbol	Value	Unit
Diode reverse voltage	V_R	80	V
Peak reverse voltage	V_{RM}	85	
Forward current	I_F	200	mA
Surge forward current, t = 1 µs	I_{FS}	4.5	A
Total power dissipation	P_{tot}		mW
BAW56, $T_S \le 31$°C		330	
BAW56S, $T_S \le 85$°C		250	
BAW56T, $T_S \le 104$°C		250	
BAW56U, $T_S \le 90$°C		250	
BAW56W, $T_S \le 103$°C		250	
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	-65 ... 150	

Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point[1]	R_{thJS}		K/W
BAW56		360	
BAW56S		260	
BAW56T		185	
BAW56U		240	
BAW56W		190	

[1]For calculation of R_{thJA} please refer to Application Note Thermal Resistance

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Electrical Characteristics at T_A = 25°C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Breakdown voltage $I_{(BR)}$ = 100 µA	$V_{(BR)}$	85	-	-	V
Reverse current	I_R				µA
V_R = 70 V		-	-	0.15	
V_R = 25 V, T_A = 150 °C		-	-	30	
V_R = 70 V, T_A = 150 °C		-	-	50	
Forward voltage	V_F				mV
I_F = 1 mA		-	-	715	
I_F = 10 mA		-	-	855	
I_F = 50 mA		-	-	1000	
I_F = 100 mA		-	-	1200	
I_F = 150 mA		-	-	1250	
AC Characteristics					
Diode capacitance V_R = 0 V, f = 1 MHz	C_T	-	-	2	pF
Reverse recovery time I_F = 10 mA, I_R = 10 mA, measured at I_R = 1mA, R_L = 100 Ω	t_{rr}	-	-	4	ns

Test circuit for reverse recovery time

D.U.T.

I_F

Oscillograph

EHN00019
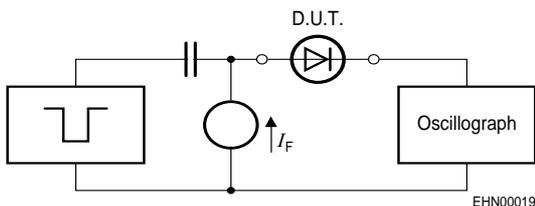
Pulse generator: t_p = 100ns, D = 0.05, t_r = 0.6ns, R_i = 50Ω

Oscillograph: R = 50Ω, t_r = 0.35ns, $C \leq$ 1pF

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Reverse current $I_R = f(T_A)$

V_R = Parameter
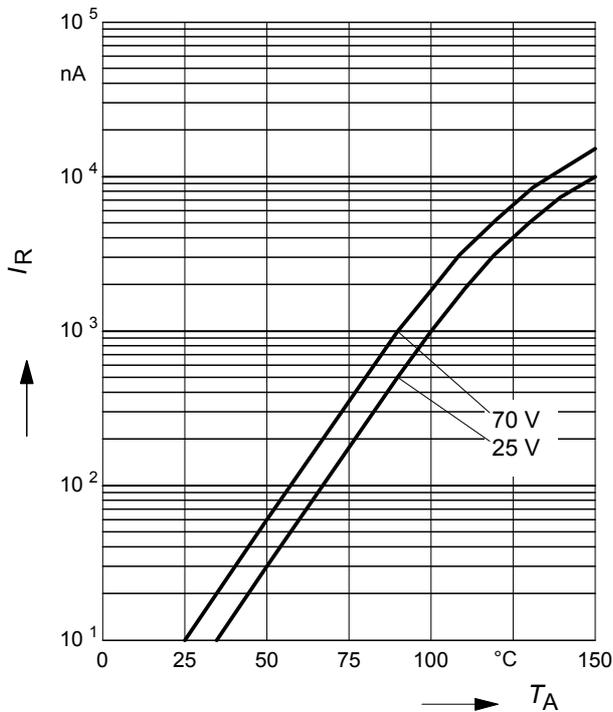
Forward Voltage $V_F = f(T_A)$

I_F = Parameter

IF = 150mA
IF = 100mA
IF = 50mA
IF = 10mA
IF = 1mA
IF = 0,1mA
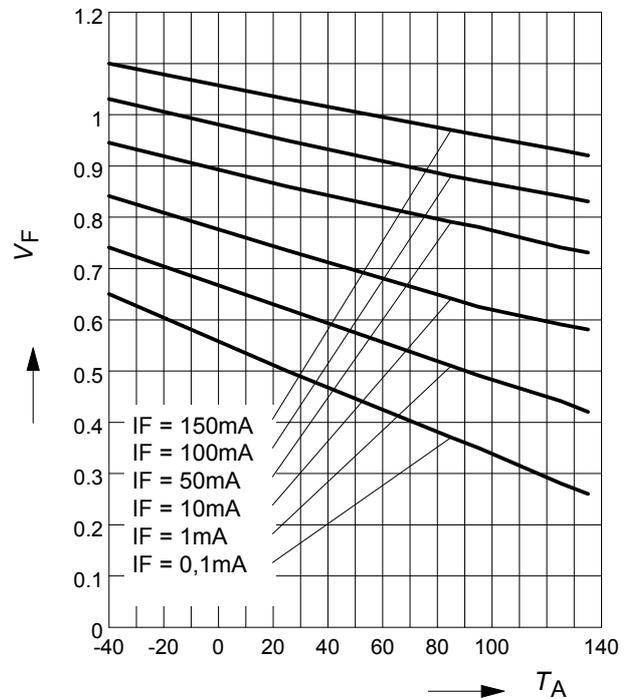
Forward current $I_F = f(V_F)$

T_A = 25°C
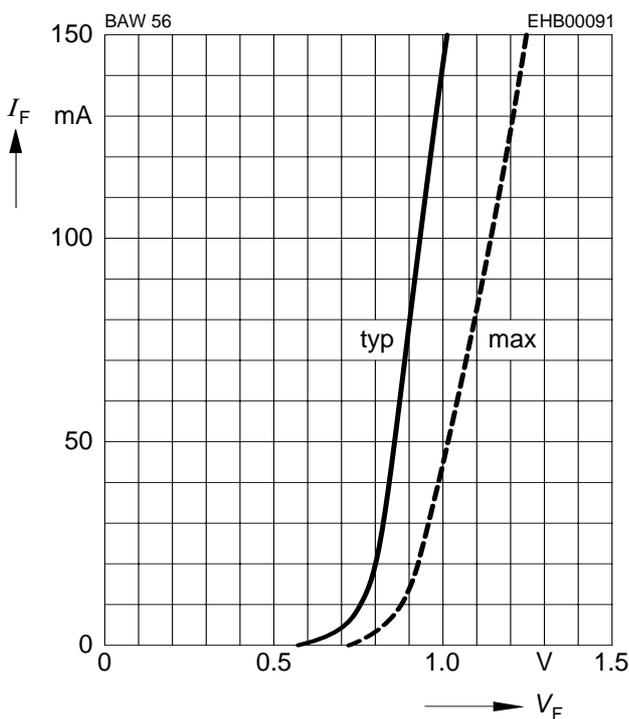
Peak forward current $I_{FM} = f(t_p)$

T_A = 25°C

BAW56

$D = \dfrac{t_p}{T}$

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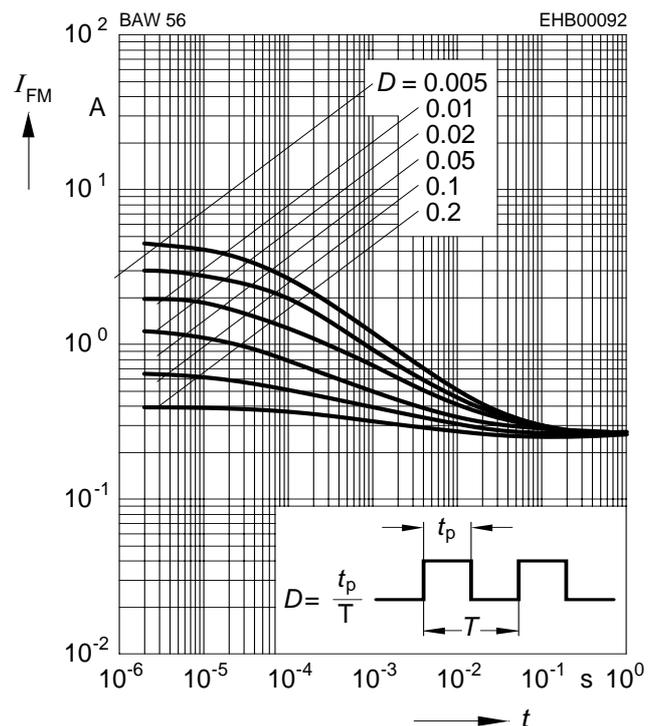
Forward current $I_F = f(T_S)$
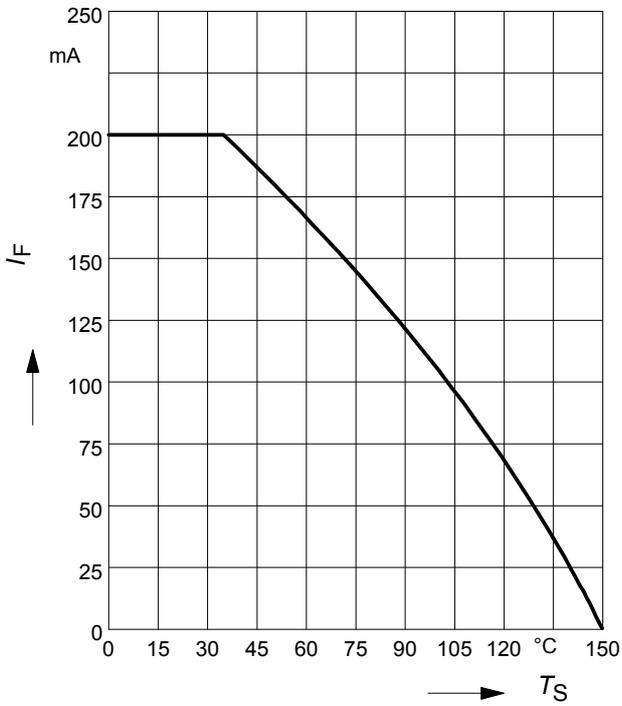
BAW56

Forward current $I_F = f(T_S)$

BAW56S
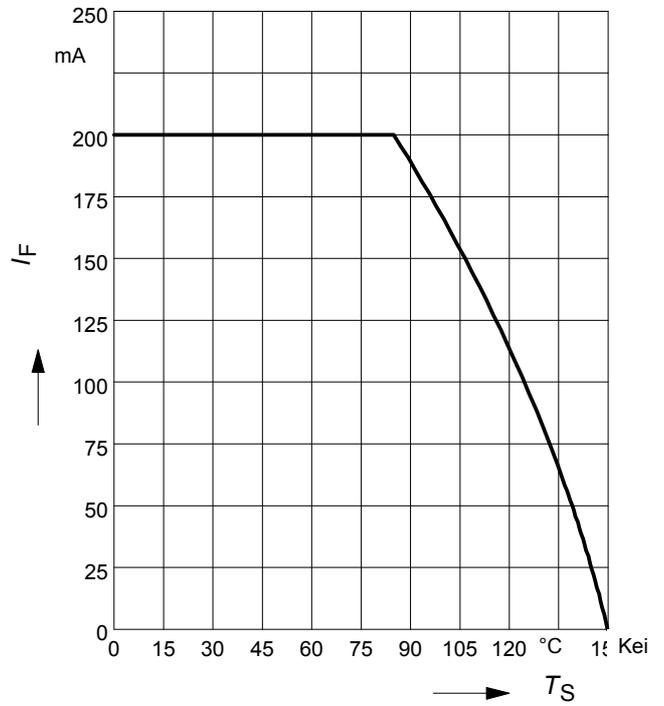
Forward current $I_F = f(T_S)$

BAW56U
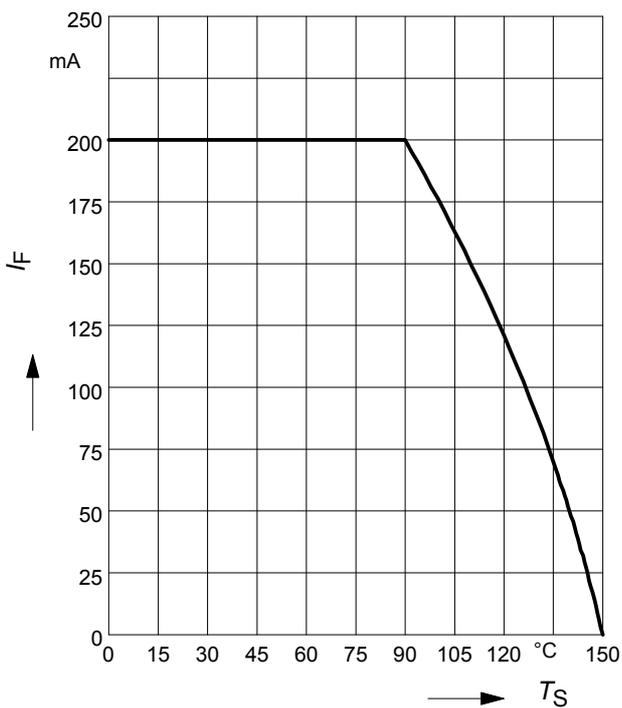
**Forward current** $I_F = f(T_S)$

BAW56W

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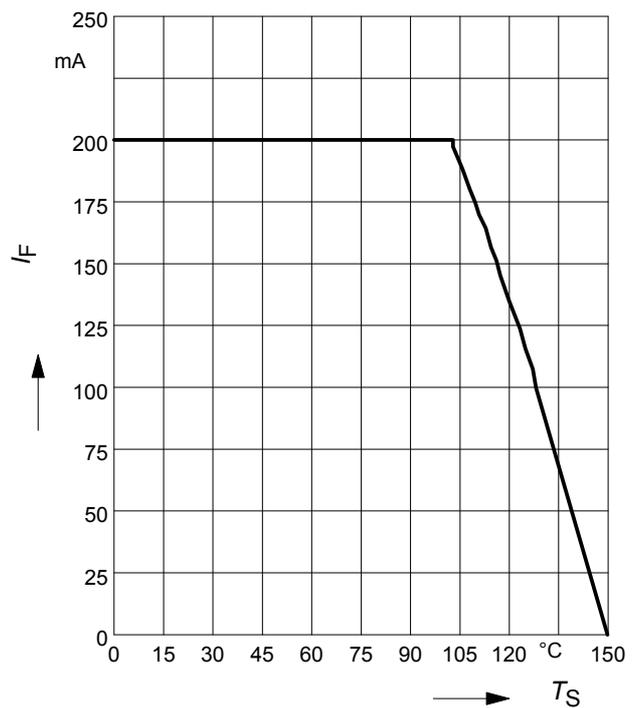
Forward current $I_F = f(T_S)$

BAW56T
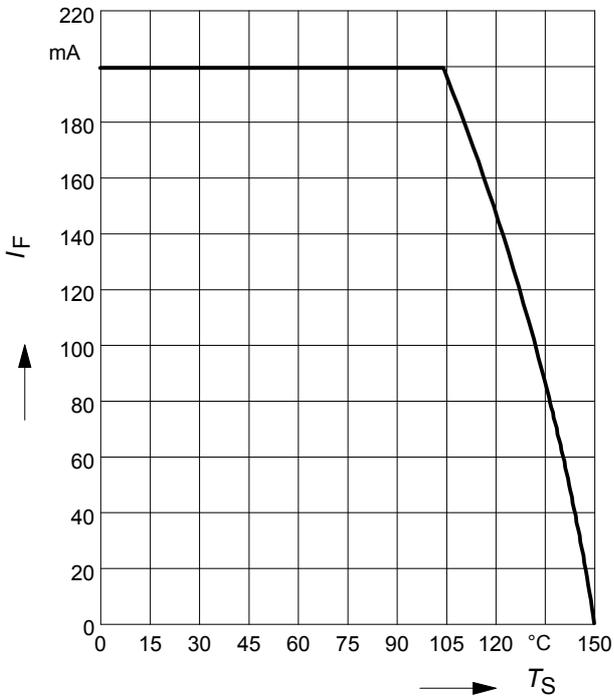
Permissible Puls Load $R_{thJS} = f(t_p)$

BAW56S
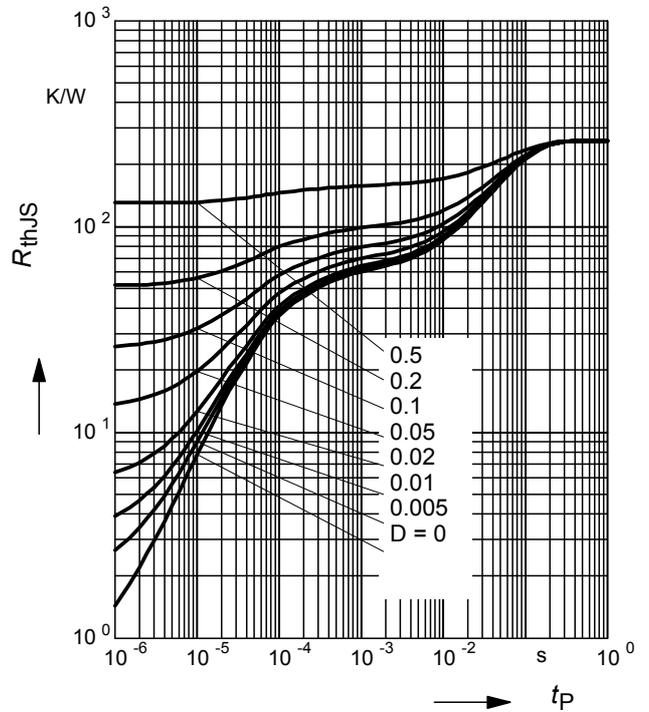
Permissible Pulse Load

$I_{Fmax}/I_{FDC} = f(t_p)$

BAW56S
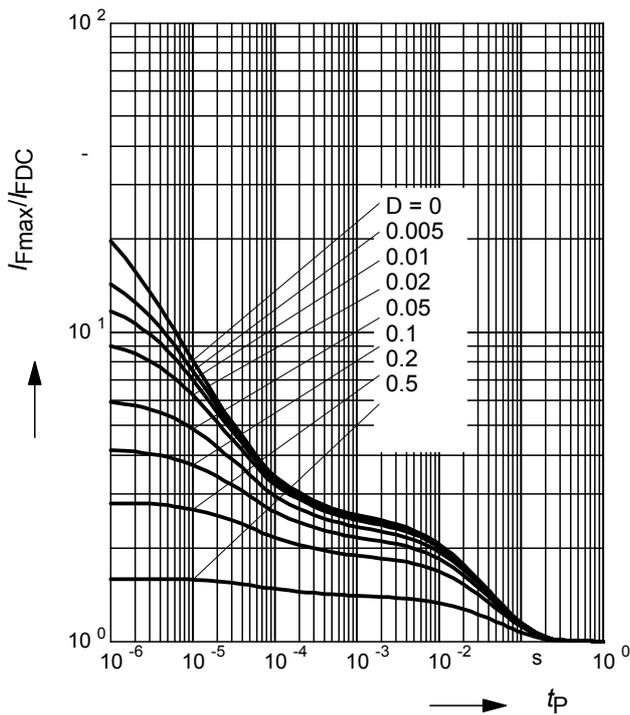
Permissible Puls Load $R_{thJS} = f(t_p)$

BAW56U

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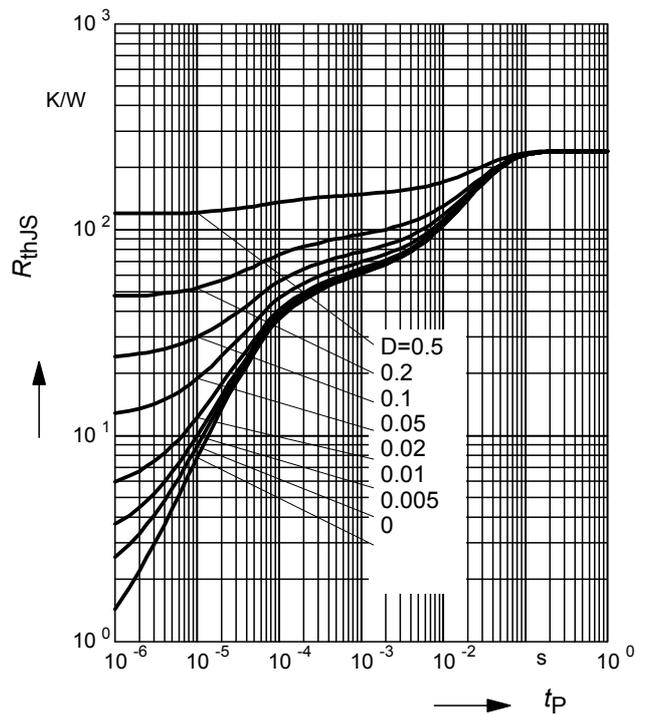
Permissible Pulse Load

$I_{Fmax}/I_{FDC} = f(t_p)$

BAW56U

Permissible Pulse Load

$I_{Fmax}/I_{FDC} = f(t_p)$
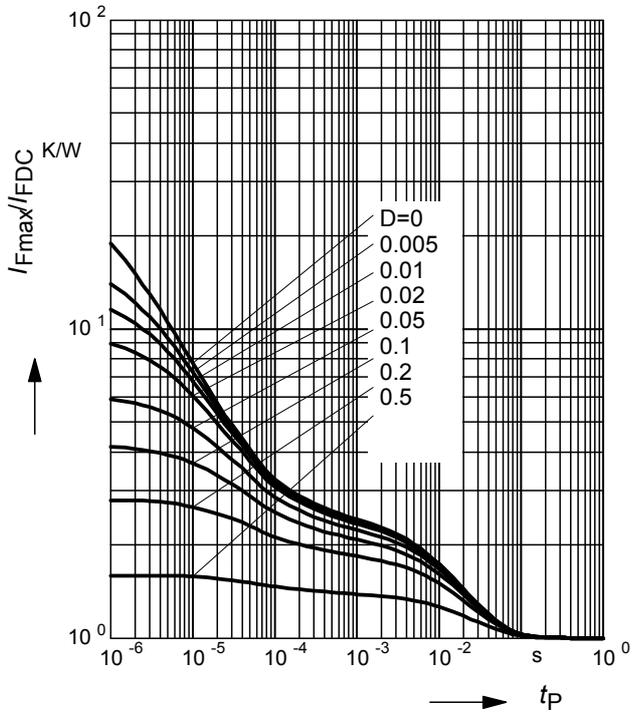
BAW56W

## Permissible Puls Load $R_{thJS} = f(t_p)$

BAW56W

Permissible Puls Load $R_{thJS} = f(t_p)$

BAW56T

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Permissible Pulse Load

$I_{Fmax}/ I_{FDC} = f (t_p)$

BAW56T